

Monolithic Amplifier

PGA-102+

Mini-Circuits

50Ω 0.05 to 6 GHz

THE BIG DEAL

- 3.3V, 83mA operation
- High IP3, 33 dBm typ. at 2 GHz
- Gain, 14.0 dB typ. at 2 GHz
- P1dB 17.5 dBm typ. at 2 GHz
- Low noise figure, 2.4dB at 2 GHz
- No external matching components required



Generic photo used for illustration purposes only

CASE STYLE: DF782

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

APPLICATIONS

- Base station infrastructure
- Portable Wireless
- CATV & DBS
- MMDS & Wireless LAN
- LTE CATV, DOCSIS 3.1WLAN

PRODUCT OVERVIEW

PGA-102+ (RoHS compliant) is an advanced wideband amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PGA-102+ has good input and output return loss over a broad frequency range without the need for external matching components and has demonstrated excellent reliability. It has repeatable performance from lot to lot and is enclosed in a SOT-89 package for very good thermal performance.

KEY FEATURES

| Feature | Advantages |
|--|---|
| Broad Band: 0.05 to 6.0 GHz | Broadband covering primary wireless communications bands: Cellular, PCS, LTE, WiMAX |
| High IP3 Versus DC power Consumption: 33 dBm typical at 2 GHz at +3.3V Supply Voltage and only 83mA | The PGA-102+ provides good IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 15 dB above the P 1dB point. This feature makes this amplifier ideal for use in: • Driver amplifiers for complex waveform up converter paths • Drivers in linearized transmit systems • Secondary amplifiers in ultra High Dynamic range receivers |
| No External Matching Components Required | Unlike competing products, Mini-Circuits PGA-102+ provides Input and Output Return Loss of 16-19 dB up to 4 GHz without the need for any external matching components |
| Low Noise Figure: 2.3 dB up to 0.8 GHz | A unique feature of the PGA-102+ which separates this design from all competitors is the low noise figure perfor- mance in combination with the high dynamic range |

REV. D ECO-011959 PGA-102+ GY/RS/CP 220823

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HIGH DYNAMIC RANGE

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ELECTRICAL SPECIFICATIONS AT 25°C, 50Ω, UNLESS NOTED OTHERWISE

| Parameter | Condition (GHz) | Min. | Тур. | Max. | Units |
|---|-----------------|------|-------------|------|-------|
| Frequency Range | | 0.05 | | 6 | GHz |
| | 0.05 | _ | 17.7 | _ | dB |
| | 0.8 | 14.4 | 15.9 | 17.4 | |
| Gain | 2.0 | _ | 14.0 | _ | |
| Gaill | 3.0 | _ | 12.5 | _ | |
| | 4.0 | _ | 11.5 | _ | |
| | 6.0 | _ | 10.4 | _ | |
| | 0.05 | _ | 14.0 | _ | dB |
| | 0.8 | 15 | 18.4 | — | |
| Input Return Loss | 2.0 | _ | 12.4 | — | |
| | 3.0 4.0 | _ | 10.5 9.4 | _ | |
| | 6.0 | | 9.4 6.7 | — | |
| | 0.05 | | 18.3 | | |
| | 0.8 | 15 | 18.6 | _ | |
| | 2.0 | - | 17.6 | _ | |
| Output Return Loss | 3.0 | _ | 17.1 | _ | dB |
| | 4.0 | _ | 15.3 | _ | |
| | 6.0 | _ | 11.0 | _ | |
| Reverse Isolation | 2.0 | | 21.9 | | dB |
| | 0.05 | _ | 17.6 | _ | dBm |
| | 0.8 | 16.0 | 17.4 | _ | |
| Output Power @1 dB compression | 2.0 | _ | 17.5 | _ | |
| Output Power @1 dB compression | 3.0 | — | 17.5 | — | |
| | 4.0 | _ | 17.3 | _ | |
| | 6.0 | - | 16.5 | - | |
| | 0.05 | | 30.8 | | dBm |
| | 0.8 | | 32.7 | | |
| Output IP3 | 2.0 | | 33.0 | | |
| | 3.0 | | 33.0 | | |
| | 4.0 | | 33.4 | | dB |
| | 6.0 | | 33.2 | | |
| | 0.05 0.8 | | 2.1 2.3 | | |
| | 2.0 | | 2.3 | | |
| Noise Figure | 3.0 | | 2.4 | | |
| | 4.0 | | 3.0 | | |
| | 6.0 | | 3.9 | | |
| Device Operating Voltage | | 3.1 | 3.3 | 3.5 | V |
| Device Operating Current | | 60 | 83 | 120 | mA |
| Device Current Variation vs. Temperature | | | 49 | - | µA/°C |
| Device Current Variation vs Voltage | | | 0.066 | | mA/mV |
| Thermal Resistance, junction-to-ground lead | | | 73 | | °C/W |

1. Measured on Mini-Circuits Characterization test board TB-313. See Characterization Test Circuit (Fig. 1)



HIGH DYNAMIC RANGE

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MAXIMUM RATINGS⁵

| Parameter | Ratings |
|-------------------------------------|----------------|
| Operating temperature (ground lead) | -40°C to 85°C |
| Storage temperature | -65°C to 150°C |
| Operating Current at 3.3V | 300mA |
| Power dissipation | 1.0W |
| Input power (CW) | +28 dBm |
| DC voltage on Pin 3 | 5.5V |

5.Permanent damage may occur if any of these limits are exceeded.

Electrical maximum ratings are not intended for continuous normal operation.

SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION



| Function | Pin Number | Description |
|------------------|------------|---|
| RFIN | 1 | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| RF-OUT and DC-IN | 3 | RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit", Fig. 2 |
| GND | 2,4 | Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance. |

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CHARACTERIZATION TEST CIRCUIT



Fig 1. Block Diagram of Test Circuit used for characterization. (DUT tested on Mini-Circuits Characterization test board TB-313) Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin= -25dBm

2. Output IP3 (OIP3): Two tones, spaced 10 MHz apart, 2.5 dBm/tone at output.

RECOMMENDED APPLICATION CIRCUIT



Cblock=0.001µF, Bias-Tee=TCBT-14+, Cbypass=0.1µF

Fig 2. Evaluation board includes case, connectors, and components soldered to PCB

PRODUCT MARKING



Marking may contain other features or characters for internal lot control



Monolithic Amplifier

ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS CLICK HERE

| | Data Table |
|--|--|
| Performance Data | Swept Graphs |
| | S-Parameter (S2P Files) Data Set (.zip file) |
| Case Style | DF782 (SOT 89) Plastic package, exposed paddle lead finish: matte-tin |
| Tape & Reel Standard quantities available on reel | F55 7" reels with 20, 50, 100, 200, 500 or 1K devices |
| Suggested Layout for PCB Design | PL-313 |
| Evaluation Board | TB-596-1+ |
| Environmental Ratings | ENV08T1 |

ESD RATING

Human Body Model (HBM): Class 1B (500 to <1000V) in accordance with ANSI/ESD STM 5.1 - 2001 Machine Model (MM): Class M1 (50V) in accordance with ANSI/ESD STM5.2-1999



Attention Observe precautions for handling electrostatic sensitive devices

MSL RATING Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL TEST FLOW CHART



NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp